### **Specifications**

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Issued Date.	Jul,28,2015	

## Messrs: Digi-key

Note: Part Number will be revised in case of specification change.

Product Type	Tuning Fork Crystal			
Series	ST3215SB			
Frequency	32.768 kHz			
Customer Part Number	-			
Customer Specification Number	-			
KYOCERA Part Number	ST3215SB32768H5WZZAP			
Remarks Pb-Free, RoHS Compliant, MSL 1				

**Customer Approval** 

Approval Signature	Approved Date	
	Department	
	Person in charge	

# Seller KYOCERA Crystal Device Corporation

(Sales Division) 6 Takeda Tobadono-cho, Fushimi-ku, Kyoto 612-8501 Japan

TEL. No. 075-604-3500 FAX. No. 075-604-3501

# Manufacturer KYOCERA Crystal Device Corporation

(Crystal Units Division) 5850, Higashine-Koh, Higashine-Shi, Yamagata

999-3701 Japan TEL. No. 0237-43-5611

FAX. No. 0237-43-5615

Design Department	Quality Assurance	Approved by	Checked by	Issued by
KYOCERA Crystal Device Corporation Crystal Unit Application Engineering Section Crystal Units Division	S.Itou	T.Soda	A.Muraoka	Y.Nozaki

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### **Revision History**

Rev.No.	Description of revision	Date	Approved by	Checked by	Issued by
0	First Edition	Jul,28,2015	T.Soda	A.Muraoka	Y.Nozaki

#### 1. APPLICATION

This specification sheet is applied to tuning fork crystal "ST3215SB".

#### 2. PART NUMBER

ST3215SB32768H5WZZAP

#### 3. RATINGS

Items	SYMB.	Rating	Unit
Operating Temperature range	Topr	-25~+75	deg. C
Storage Temperature range	Tstg	-55~+125	deg. C

#### 4. CHARACTERISTICS

#### **4-1 ELECTRICAL CHARACTERISTICS**

Itam	Cumbal	Electrical Specification				
Item	Symbol	Condition	Min	Тур.	Max	Unit
Nominal Frequency	fo	Ta = 25 deg. C		32.768		kHz
Frequency Tolerance	df/fo	Ta = 25 deg.C				
Frequency Stability	df/T	Operating Temperature	-250		250	ppm
Aging	df/F	Ta = 25 deg. C 1year				
Load Capacitance	CL			12.5		pF
Equivalent series resistance	R1				70	kΩ
Q-Value	Q		13000			
Motional capacitance	C1		3.0		4.4	fF
Shunt capacitance	Co		0.6		1.2	pF
Turning point	Тр		20		30	deg. C
Secondary temperature	К		4.0			10 <sup>-8</sup> /degC <sup>2</sup>
Coefficient	N.		-4.0			10 /degC
Drive level	DL			0.1	0.5	μW
Insulation resistance	IR		500			MΩ
(between electrodes)	IIX		300			IVIS 2

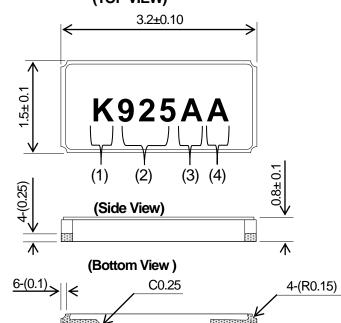
#### **4-2 MOISTURE SENSITIVITY LEVEL**

Level 1

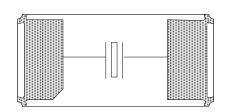
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#### 5. APPEARANCES, DIMENSIONS OUTLINE DIMENSIONS (not to scale) (TOP VIEW)



#### **CONNECTION (TOP VIEW)**



UNIT:mm

#### **MARKING**

(1) Identification

 $\leftarrow$ 

1.70

Κ

(2) Date Code(3 Digits)

Last 1 digit of year and week Code.

(3) Load Capacitance

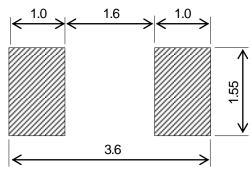
(Example) 12.5pF → A

(4) Management number

Alphabet or Number 1digit.

\*The font of marking above is for reference purpose.

#### **6. RECOMMENDED LAND PATTERN**



UNIT:mm

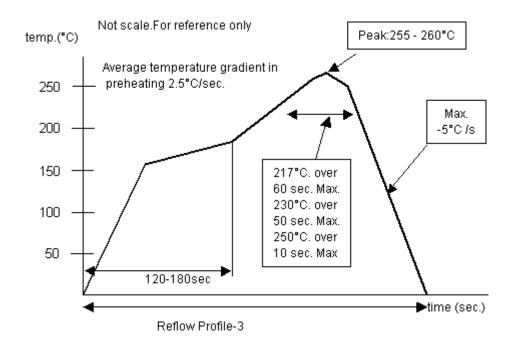
#### 7. RELIABILITY

Frequency Stability and ESR Stability After stressing.

	TEST ITEM	Frequency Stability	ESR Stability	Remarks
		(ppm)	(%)	
7.1	Low temp. use/storage	±5		
7.2	High temp. use/storage	±5		
7.3	Shock	± 20		l
7.4	Vibration	±5	L 20	To 25 dog C
7.5	Soldering iron resistance	±5	± 30	Ta=25 deg. C
7.6	Manual hot gas resistance	± 10		
7.7	High temp. With humidity	±5		
7.8	Temperature cycle	±5		

#### 8. REFLOW PROFILE

#### Pb-free reflow requirements for soldering heat resistance



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#### 9. Cautions for use

#### (1) Soldering upon mounting

Characteristics may be affected when Solder paste or conductive glue comes in contact with product lid or surface.

#### (2) When using mounting machine

Please minimize the shock when using mounting machine to avoid any excess stress to the product.

#### (3) Conformity of a circuit

We strongly recommend to make sure that Negative resistance (Gain) of IC is designed to be 3 times the ESR (Equivalent Series Resistance) of Crystal unit.

#### 10. Storage conditions

Please store product in below conditions, and use within 6 months.

Temperature +18 to +30°C, and Humidity of 20 to 70 % in the packaging condition.

#### 11. Manufacturing location

Kyocera Crystal Device Corporation Shiga Yohkaichi Plant

#### 12. Quality Assurance

To be guaranteed by Kyocera Crystal Device Quality Assurance Division

#### 13. Quality guarantee

When Kyocera Crystal Device Corporation rooted failure occurs within 1 year after its delivery, substitute product will be arranged based on discussion. Quality guarantee of product after 1 year of its delivery will be waivered.

#### 14. Others

In case of any questions or opinions regarding the Specification, please have it in written manner within 45 days after issued date.